

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China







Low-Power D-Type Transparent Latch with 3-State Output

The NL17SG373 MiniGate TM is an advanced high-speed CMOS D-Type Transparent Latch with 3-State Output in ultra-small footprint.

The NL17SG373 input structures provide protection when voltages up to 5.5 V are applied, regardless of the supply voltage.

This device is fully specified for partial power–down applications using I_{OFF} . The I_{OFF} circuitry disables the output, preventing the damaging backflow current through the device when it is powered down.

Features

- Wide Operating V_{CC} Range: 0.9 V to 3.6 V
- High Speed: $t_{PD} = 2.4 \text{ ns}$ (Typ) @ $V_{CC} = 3.0 \text{ V}$, $C_L = 15 \text{ pF}$
- Low Power Dissipation: $I_{CC} = 0.5 \mu A$ (Max) at $T_A = 25^{\circ}C$
- 5.5 V Overvoltage Tolerant (OVT) Input Pins
- Ultra-Small Packages
- These Devices are Pb-Free and are RoHS Compliant

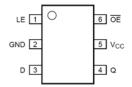


Figure 1. SC88 (Top View)

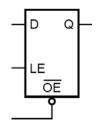


Figure 2. Logic Symbol



ON Semiconductor®

http://onsemi.com

MARKING DIAGRAMS



SC-88 DF SUFFIX CASE 419B



AG = Device Code

M = Date Code*

Pb-Free Package

(Note: Microdot may be in either location)

*Date Code orientation and/or position may vary depending upon manufacturing location.

PIN ASSIGNMENT

Pin	Function
1	LE
2	GND
3	D
4	Q
5	V _{CC}
6	ŌĒ

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 9 of this data sheet.

FUNCTION TABLE

	Input			Output	
ŌĒ	LE	D	Internal Latch	Q	Operating Mode
L	Н	L	L	L	Enable and Read Register
L	Н	Н	Н	Н	(Transparent Mode)
L	L	L	L	L	Latch and Read Register
L	L	Н	Н	Н	
Н	Х	Х	Х	Z	Latch Register and Disable Output

MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V _{CC}	DC Supply Voltage	-0.5 to +5.5	V
V _{IN}	DC Input Voltage	-0.5 to +5.5	V
V _{OUT}	DC Output Voltage	-0.5 to V _{CC} + 0.5	٧
I _{IK}	DC Input Diode Current V _{IN} < GND	-50	mA
I _{OK}	DC Output Diode Current V _{OUT} < GND, V _{OUT} > V _{CC}	±50	mA
ΙO	DC Output Source/Sink Current	±20	mA
I _{CC}	DC Supply Current Per Supply Pin	±50	mA
I _{GND}	DC Ground Current per Ground Pin	±50	mA
T _{STG}	Storage Temperature Range	-65 to +150	°C
TL	Lead Temperature, 1 mm from Case for 10 Seconds	260	°C
T _J	Junction Temperature Under Bias	150	°C
MSL	Moisture Sensitivity	Level 1	
F _R	Flammability Rating Oxygen Index: 28 to 34	UL 94 V-0 @ 0.125 in	
V _{ESD}	ESD Withstand Voltage Human Body Mode (Note 2) Machine Model (Note 3)	> 3000 > 200	V
I _{LATCHUP}	Latchup Performance Above V _{CC} and Below GND at 125°C (Note 4)	±100	mA

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Measured with minimum pad spacing on an FR4 board, using 10 mm-by-1 inch, 2 ounce copper trace no air flow.

- Tested to EIA / JESD22-A114-A.
 Tested to EIA / JESD22-A115-A.
- 4. Tested to EIA / JESD78.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Min	Max	Unit
V _{CC}	Positive DC Supply Voltage	0.9	3.6	V
V _{IN}	Digital Input Voltage	0	3.6	V
V _{OUT}	Output Voltage Active Mode	0	V _{CC}	V
T _A	Operating Free–Air Temperature	- 55	+125	°C
Δt / ΔV	Input Transition Rise or Fail Rate V_{CC} = 3.3 V \pm 0.3 V	0	10	nS/V

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

DC ELECTRICAL CHARACTERISTICS

						T _A = 25°	С	–55°C to	∆ = o +125°C		
Symbol	Parameter	С	Conditions V _{CC} (V)	Min	Тур	Max	Min	Max	Unit		
V _{IH}	High-Level			0.9	V _{CC}			V _{CC}		V	
	Input Voltage			1.1 to 1.3	0.7 x V _{CC}			0.7 x V _{CC}			
				1.4 to 1.6	0.65 x V _{CC}			0.65 x V _{CC}			
				1.65 to 1.95	0.65 x V _{CC}			0.65 x V _{CC}			
				2.3 to 2.7	1.7			1.7		1	
				3.0 to 3.6	2.0			2.0			
V _{IL}	Low-Level			0.9			GND		GND	V	
	Input Voltage			1.1 to 1.3			0.3 x V _{CC}		0.3 x V _{CC}		
				1.4 to 1.6			0.35 x V _{CC}		0.35 x V _{CC}		
				1.65 to 1.95			0.35 x V _{CC}		0.35 x V _{CC}		
			2.3 to 2.7			0.7		0.7			
				3.0 to 3.6			0.8		0.8		
V _{OH}	V _{OH} High-Level Output Voltage	High-Level	V _{IN} =	$I_{OH} = -20 \mu A$	0.9	0.75			0.75		٧
		V _{IH} or V _{IL}	$I_{OH} = -0.3 \text{ mA}$	1.1 to 1.3	0.75 x V _{CC}			0.75 x V _{CC}			
				I _{OH} = -1.7 mA	1.4 to 1.6	0.75 x V _{CC}			0.75 x V _{CC}		
			$I_{OH} = -3.0 \text{ mA}$	1.65 to 1.95	V _{CC} – 0.45			V _{CC} - 0.45			
			$I_{OH} = -4.0 \text{ mA}$	2.3 to 2.7	2.0			2.0		1	
			$I_{OH} = -8.0 \text{ mA}$	3.0 to 3.6	2.48			2.48			
V_{OL}	Low-Level	V _{IN} =	I _{OL} = 20 μA	0.9			0.1		0.1	٧	
	Output Voltage	V _{IH} or V _{IL}	I _{OL} = 0.3 mA	1.1 to 1.3			0.25 x V _{CC}		0.25 x V _{CC}		
			I _{OL} = 1.7 mA	1.4 to 1.6			0.25 x V _{CC}		0.25 x V _{CC}		
			I _{OL} = 3.0 mA	1.65 to 1.95			0.45		0.45		
			I _{OL} = 4.0 mA	2.3 to 2.7			0.4		0.4		
			I _{OL} = 8.0 mA	3.0 to 3.6			0.4		0.4	1	
I _{IN}	Input Leakage Current	0 ≤	V _{IN} ≤ 3.6 V	0 to 3.6			±0.1		±0.5	μΑ	
I _{CC}	Quiescent Supply Current	V _{IN} =	V _{IN} = V _{CC} or GND				0.5		10	μА	
l _{OZ}	3-State Output Leakage Current	V _{IN}	= V _{IH} or V _{IL} ; _T = 0 to 3.6 V	0.9 to 3.6			0.1		1	μА	

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

AC ELECTRICAL CHARACTERISTICS (Input $t_{\text{f}} = t_{\text{f}} = 3.0 \text{ ns}$)

					T _A = 25 °C		–55°C to	4 = 0 +125°C	
Symbol	Parameter	Test Condition	V _{CC} (V)	Min	Тур	Max	Min	Max	Uni
t _{PLH} ,	Propagation Delay,	C _L = 10 pF,	0.9	-	15.3	-	-	-	ns
t _{PHL}	D to Q	$R_L = 1 M\Omega$	1.1 to 1.3	-	6.3	12.3	1.0	14.4	
			1.4 to 1.6	-	4.4	8.1	1.0	9.4	
			1.65 to 1.95	-	3.6	6.2	0.5	6.7	
			2.3 to 2.7	_	2.6	3.9	0.5	4.4	1
			3.0 to 3.6	-	2.1	3.1	0.5	3.7	
		C _L = 15 pF,	0.9	-	17.7	_	-	-	ns
		$R_L = 1 M\Omega$	1.1 to 1.3	_	7.1	13.6	1.0	15.6	
			1.4 to 1.6	-	5.0	9.2	1.0	10.4	
			1.65 to 1.95	-	4.1	6.9	1.0	7.1	
			2.3 to 2.7	_	2.9	4.4	0.5	5.0	1
			3.0 to 3.6	_	2.4	3.4	0.5	3.9	
	C _L = 30 pF,	0.9	-	29	-	-	-	ns	
	$R_L = 1 M\Omega$	1.1 to 1.3	-	9.3	17.3	1.0	21.2		
		1.4 to 1.6	-	6.4	11.6	1.0	12.6	1	
			1.65 to 1.95	-	5.3	9.1	1.0	9.6	
		2.3 to 2.7	-	4	5.7	1.0	6.1]	
			3.0 to 3.6	-	3.3	4.4	1.0	4.8	1
t _{PLH} ,	Propagation Delay,	$C_L = 10 \text{ pF},$	0.9	-	15.3	-	-	-	ns
t _{PHL}	LE to Q	$R_L = 1 M\Omega$	1.1 to 1.3	-	6.3	12.3	1.0	14.4	1
			1.4 to 1.6	-	4.4	8.1	1.0	9.4	
			1.65 to 1.95	-	3.6	6.2	0.5	6.7	
			2.3 to 2.7	-	2.6	3.9	0.5	4.4	
			3.0 to 3.6	-	2.1	3.1	0.5	3.7	
		$C_L = 15 pF$,	0.9	-	17.7	-	-	-	n
		$R_L = 1 \text{ M}\Omega$	1.1 to 1.3	-	7.1	13.6	1.0	15.6	1
			1.4 to 1.6	-	5.0	9.2	1.0	10.4	
			1.65 to 1.95	-	4.1	6.9	1.0	7.1	
			2.3 to 2.7	-	2.9	4.4	0.5	5.0	1
			3.0 to 3.6	-	2.4	3.4	0.5	3.9	1
		C _L = 30 pF,	0.9	_	29	_	-	-	n
		$R_L = 1 \text{ M}\Omega$	1.1 to 1.3	_	9.3	17.3	1.0	21.2	1
			1.4 to 1.6	_	6.4	11.6	1.0	12.6	1
		1.65 to 1.95	-	5.3	9.1	1.0	9.6		
			2.3 to 2.7	-	4	5.7	1.0	6.1	1
			3.0 to 3.6	-	3.3	4.4	1.0	4.8	1

AC ELECTRICAL CHARACTERISTICS (Input $t_{\text{f}} = t_{\text{f}} = 3.0 \text{ ns}$)

					T _A = 25 °C		-55°C to	A = D +125°C	
Symbol	Parameter	Test Condition	V _{CC} (V)	Min	Тур	Max	Min	Max	Unit
			0.9	İ	18.9	-	-	-	
			1.1 to 1.3	ı	6.0	10.2	1	10.6	
		C ₁ = 10 pF.	1.4 to 1.6	ı	4.5	6.5	1	7.0	
		$C_L = 10 \text{ pF},$ $R_L = 5 \text{ k}\Omega$	1.65 to 1.95	ı	3.9	5.4	1	5.8	ns
			2.3 to 2.7	1	2.5	3.5	1	3.8	
			3.0 to 3.6	_	2.1	2.7	1	3	
			0.9	_	22	-	-	-	
			1.1 to 1.3	ı	6.8	11.6	1	12.1	
+	Output Enable	C. 15 pE	1.4 to 1.6	Ì	5.1	7.2	1	7.9	
t_{PZH} , t_{PZL}	Time, OE to Q	$C_L = 15 \text{ pF},$ $R_L = 5 \text{ k}\Omega$	1.65 to 1.95	-	4.4	6.1	1	6.5	ns
			2.3 to 2.7	-	2.9	3.9	1	4.2	1
			3.0 to 3.6	-	2.3	3	1	3.3	1
			0.9	-	31.8	-	-	_	
			1.1 to 1.3	-	9.1	15.7	1	16.2	1
		$C_L = 30 \text{ pF},$ $R_L = 5 \text{ k}\Omega$	1.4 to 1.6	-	6.7	9.5	1	10.5	1
			1.65 to 1.95	-	5.7	7.9	1	8.6	ns
			2.3 to 2.7	-	3.8	5	1	5.5	1
			3.0 to 3.6	-	2.9	3.8	1	4.2	1
			0.9	-	11.3	-	-	-	
			1.1 to 1.3	-	5.3	8.3	1	8.4	ns
			1.4 to 1.6	-	4.1	5.8	1	6.1	
		$C_L = 10 \text{ pF},$ $R_L = 5 \text{ k}\Omega$	1.65 to 1.95	-	4.2	5.7	1	5.9	
			2.3 to 2.7	-	3.0	4	1	4.2	
			3.0 to 3.6	-	3.4	4.7	1	5	1
			0.9	-	11	-	-	-	
			1.1 to 1.3	-	5.8	8.2	1	11	1
			1.4 to 1.6	-	3.9	5.9	1	8	1
$t_{PLZ},$	Output Disable Time, _{OE} to Q	$C_L = 15 \text{ pF},$ $R_L = 5 \text{ k}\Omega$	1.65 to 1.95	-	4.5	6.6	1	7.4	ns
			2.3 to 2.7	_	3.2	4.3	1	5.1	1
			3.0 to 3.6	_	4.8	6.2	1	6.7	1
			0.9	_	17.7	-	_	_	†
			1.1 to 1.3	_	9.9	15.7	1	16	1
			1.4 to 1.6	_	7.7	10.8	1	11.6	1
		$C_L = 30 \text{ pF},$ $R_L = 5 \text{ k}\Omega$	1.65 to 1.95	-	6	12.9	1	12.9	ns
			2.3 to 2.7	_	5	9.1	1	9.5	1
			3.0 to 3.6	_	4	12.5	1	13	1

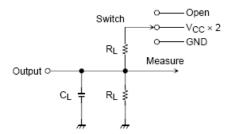
AC ELECTRICAL CHARACTERISTICS (Input $t_r = t_f = 3.0 \text{ ns}$)

				T _A = 25 °C			T _A –55°C to		
Symbol	Parameter	Test Condition	V _{CC} (V)	Min	Тур	Max	Min	Max	Unit
C _{IN}	Input Capacitance		0 to 3.6		1.5	-	-	-	pF
Co	Output Capacit- ance	V _O = GND	0		3	-	-	-	pF
			0.9	-	1.6	-		-	
			1.1 to 1.3	-	1.7	-		-	
	Power dissipation	f =10 MHz;	1.4 to 1.6	-	1.8	-		-	
C _{PD}		$V_I = GND$ to V_{CC}	1.65 to 1.95	-	1.9	-		-	pF
			2.3 to 2.7	-	2.2	-		-	
			3.0 to 3.6	_	2.7	-		-	

^{5.} C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the dynamic operating current consumption without load. Average operating current can be obtained by the equation $I_{CC(OPR)} = C_{PD} \cdot V_{CC} \cdot f_{in} + I_{CC}$. C_{PD} is used to determine the no–load dynamic power consumption: $P_D = C_{PD} \cdot V_{CC}^2 \cdot f_{in} + I_{CC} \cdot V_{CC}$.

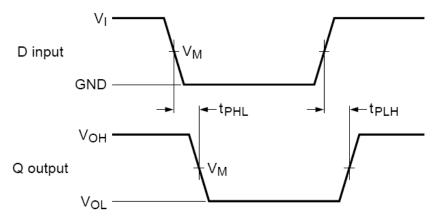
TIMING REQUIREMENTS (Input $t_r = t_f = 3.0 \text{ ns}$; $C_L = 5 \text{ pF}$, 10 pF, 15 pF and 20 pF)

					T _A = 25 °C	;	T _A -55°C to	= +125°C	
Symbol	Parameter	Test Condition	V _{CC} (V)	Min	Тур	Max	Min	Max	Unit
t _W Pulse Width, LE			0.9	-	4.0	-	-	-	
			1.1 to 1.3	-	0.7	-	2.1	-	
			1.4 to 1.6	-	0.5	_	1.3	-	
	High	1.65 to 1.95	_	0.4	-	1.0	-	ns	
			2.3 to 2.7	-	0.3	-	0.8	-	
			3.0 to 3.6	-	0.2	-	0.8	-	
			0.9	-	2.1	-	-	-	
	Set-Up Time, D to LE	High or Low	1.1 to 1.3	-	0.5	-	2.7	-	ns
			1.4 to 1.6	-	0.3	-	1.5	-	
t _{SU}			1.65 to 1.95	-	0.3	-	1.2	-	
			2.3 to 2.7	_	0.2	-	0.9	-	
			3.0 to 3.6	-	0.2	-	0.7	-	
			0.9	-	-2.8	-	-	-	
			1.1 to 1.3	-	-0.7	-	-0.1	-	
			1.4 to 1.6	-	-0.4	-	-0.1	-	
t _H	Hold Time D to LE	High or Low	1.65 to 1.95	_	-0.4	-	0	_	ns
			2.3 to 2.7	-	-0.3	-	0.2	-	
			3.0 to 3.6	-	-0.4	-	0.3	-	



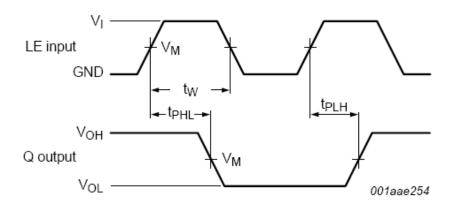
Characteristics	Switch
t _{pLH} , t _{pHL}	Open
t _P LZ, t _P ZL	V _{CC} × 2
t _{pHZ} , t _{pZH}	GND

Figure 3. Test Circuit



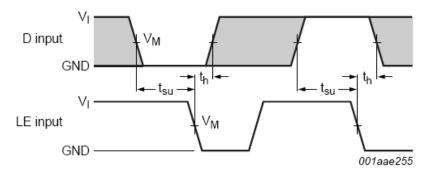
Logic levels: V_{OL} and V_{OH} are typical output voltage levels that occur with the output load.

Figure 4. t_{PLH} , t_{PHL} Waveforms (D to Q)



Logic levels: V_{OL} and V_{OH} are typical output voltage levels that occur with the output load.

Figure 5. t_{PLH} , t_{PHL} , t_{W} Waveforms (LE to Q)

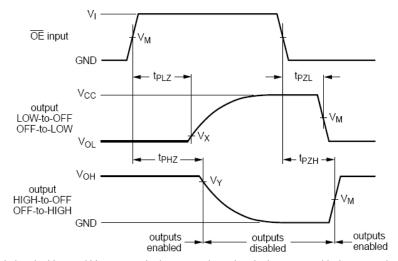


Logic levels: V_{OL} and V_{OH} are typical output voltage levels that occur with the output load.

Figure 6. t_{SU}, t_H Waveforms (D to LE)

MEASUREMENT POINTS FOR FIGURES 4, 5 AND 6

Supply Voltage		Input	Output	
V _{CC}	V _M	V _I	$t_r = t_f$	V _M
0.9 V to 3.6 V	0.5 x V _{CC}	V _{CC}	≤ 3.0 ns	0.5 x V _{CC}



Logic levels: V_{OL} and V_{OH} are typical output voltage levels that occur with the output load.

Figure 7. t_{PLZ}, t_{PHZ}, t_{PZH}, t_{PZL} Waveforms ($\overline{\text{OE}}$ to Q)

MEASUREMENT POINTS FOR FIGURE 7

Supply Voltage	Input			Output			
V _{CC}	V _M	V _I	t _r = t _f	V _M	V _X	V _Y	
0.9 V	0.5 x V _{CC}	V _{CC}	≤ 3.0 ns	0.5 x V _{CC}	V _{OL} + 0.1 V	V _{OH} – 0.1 V	
1.1 V to 1.3 V	0.5 x V _{CC}	V _{CC}	≤ 3.0 ns	0.5 x V _{CC}	V _{OL} + 0.1 V	V _{OH} – 0.1 V	
1.4 V to 1.6 V	0.5 x V _{CC}	V _{CC}	≤ 3.0 ns	0.5 x V _{CC}	V _{OL} + 0.1 V	V _{OH} – 0.1 V	
1.65 V to 1.95 V	0.5 x V _{CC}	V _{CC}	≤ 3.0 ns	0.5 x V _{CC}	V _{OL} + 0.15 V	V _{OH} – 0.15 V	
2.3 V to 2.7 V	0.5 x V _{CC}	V _{CC}	≤ 3.0 ns	0.5 x V _{CC}	V _{OL} + 0.15 V	V _{OH} – 0.15 V	
3.0 V to 3.6 V	0.5 x V _{CC}	V _{CC}	≤ 3.0 ns	0.5 x V _{CC}	V _{OL} + 0.3 V	V _{OH} – 0.3 V	

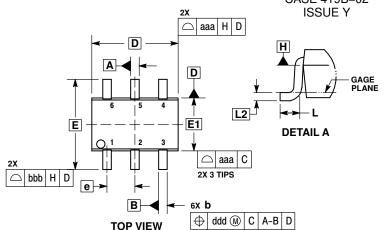
ORDERING INFORMATION

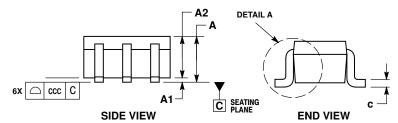
Device	Package	Shipping [†]	
NL17SG373DFT2G	SC-88 / SOT-363 / SC-70-6 (Pb-Free)	3000 / Tape & Reel	

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

PACKAGE DIMENSIONS

SC-88/SC70-6/SOT-363 CASE 419B-02

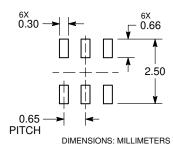




- DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994. CONTROLLING DIMENSION: MILLIMETERS. DIMENSIONS D AND E1 DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.20 PER END. DIMENSIONS D AND E1 AT THE OUTERMOST EXTREMES OF
- THE PLASTIC BODY AND DATUM H.
 DATUMS A AND B ARE DETERMINED AT DATUM H.
- DIMENSIONS 6 AND 6 APPLY TO THE FLAT SECTION OF THE LEAD BETWEEN 0.08 AND 0.15 FROM THE TIP.
- DIMENSION 6 DOES NOT INCLUDE DAMBAR PROTRUSION.
 ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 TOTAL IN
 EXCESS OF DIMENSION 6 AT MAXIMUM MATERIAL CONDITION. THE DAMBAR CANNOT BE LOCATED ON THE LOWER RADIUS OF THE FOOT.

	MILLIMETERS			INCHES		
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α			1.10			0.043
A1	0.00		0.10	0.000		0.004
A2	0.70	0.90	1.00	0.027	0.035	0.039
b	0.15	0.20	0.25	0.006	0.008	0.010
С	0.08	0.15	0.22	0.003	0.006	0.009
D	1.80	2.00	2.20	0.070	0.078	0.086
Е	2.00	2.10	2.20	0.078	0.082	0.086
E1	1.15	1.25	1.35	0.045	0.049	0.053
е	0.65 BSC			0.026 BSC		
L	0.26	0.36	0.46	0.010	0.014	0.018
L2	0.15 BSC			0.006 BSC		
aaa	0.15			0.006		
bbb	0.30			0.012		
ccc	0.10			0.004		
ddd	0.10			0.004		

RECOMMENDED **SOLDERING FOOTPRINT***



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

MiniGate is a trademark of Semiconductor Components Industries, LLC (SCILLC).

ON Semiconductor and un are registered trademarks of Semiconductor Components Industries, LLC (SCILLC). SCILLC owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of SCILLC's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. SCILLC reserves the right to make changes without further notice to any products herein. SCILLC makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does SCILLC assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. "Typical" parameters which may be provided in SCILLC data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. SCILLC does not convey any licenses under its patent rights nor the rights of others. SCILLC products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the SCILLC product could create a situation where personal injury or death may occur. Should Buyer purchase or use SCILLC products for any such unintended or unauthorized application, Buyer shall indemnify and hold SCILLC and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that SCILLC was negligent regarding the design or manufacture of the part. SCILLC is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor P.O. Box 5163, Denver, Colorado 80217 USA **Phone**: 303–675–2175 or 800–344–3860 Toll Free USA/Canada

Fax: 303-675-2176 or 800-344-3867 Toll Free USA/Canada Email: orderlit@onsemi.com

N. American Technical Support: 800-282-9855 Toll Free

Europe, Middle East and Africa Technical Support: Phone: 421 33 790 2910

Japan Customer Focus Center

Phone: 81–3–5817–1050

ON Semiconductor Website: www.onsemi.com

Order Literature: http://www.onsemi.com/orderlit

For additional information, please contact your local Sales Representative